SCS215KGHR

Automotive Grade SiC Schottky Barrier Diode

Datasheet

V_R	1200V
I _F	15A
Q_{C}	51nC

Outline TO-220AC

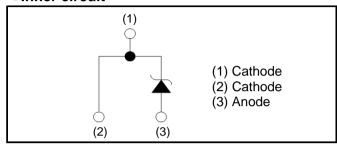
Features

- 1) AEC-Q101 qualified
- 2) Low forward voltage
- 3) Negligible recovery time/current
- 4) Temperature independent switching behavior

Applications

- · On Board Charger
- DC/DC Converter
- · Wireless Charger
- EV Charger

•Inner circuit



Packaging specifications

	<u> </u>	- .
	Packaging	Tube
	Reel size (mm)	-
Type	Tape width (mm)	-
Туре	Basic ordering unit (pcs)	50
	Packing code	С
	Marking	SCS215KG

● Absolute maximum ratings (T_i = 25°C)

Parameter		Symbol	Value	Unit
Reverse voltage (re	petitive peak)	V_{RM}	1200	V
Reverse voltage (D	C)	V _R	1200	V
Continuous forward	current (T _c = 140°C)	I _F	15	А
Surge non-	PW=10ms sinusoidal, T _j =25°C		62	А
repetitive forward	PW=10ms sinusoidal, T _j =150°C	I _{FSM}	46	А
current	PW=10μs square, T _j =25°C		240	А
Repetitive peak forward current		I _{FRM}	68 *1	А
PW=10ms, T _j =25°C		$\int i^2 dt$	19	A ² s
i ² t value	PW=10ms, T _j =150°C	J i⁻dt	10	A ² s
Total power dissipation		P_{D}	180 ^{*2}	W
Junction temperature		T _j	175	°C
Range of storage temperature		T_{stg}	-55 to +175	°C

^{*1} T_c=100°C, T_i=150°C, Duty cycle=10% *2 T_c=25°C

•Electrical characteristics $(T_j = 25^{\circ}C)$

Parameter	Symbol	Conditions	Values			Unit
			Min.	Тур.	Max.	Unit
DC blocking voltage	V_{DC}	I _R =0.3mA	1200	-	-	V
	V _F	I _F =15A,T _j =25°C	-	1.4	1.6	V
Forward voltage		I _F =15A,T _j =150°C	-	1.8	-	V
		I _F =15A,T _j =175°C	-	1.9	-	V
Reverse current	I _R	V _R =1200V,T _j =25°C	-	15	300	μΑ
		V _R =1200V,T _j =150°C	-	120	-	μΑ
		V _R =1200V,T _j =175°C	-	195	-	μΑ
Total capacitance	С	V _R =1V,f=1MHz	-	790	-	pF
		V _R =800V,f=1MHz	-	64	-	pF
Total capacitive charge	Q _C	V _R =800V,di/dt=500A/μs	-	51	-	nC
Switching time	t _C	V _R =800V,di/dt=500A/μs	-	18	-	ns

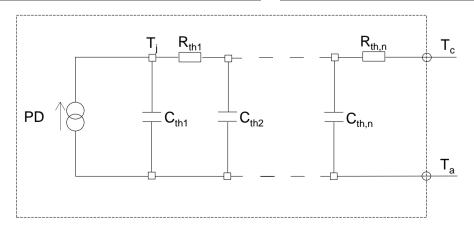
●Thermal characteristics

Parameter	Symbol	Conditions	Values			Unit
			Min.	Тур.	Max.	Offic
Thermal resistance	$R_{\text{th(j-c)}}$	-	-	0.67	0.80	°C/W

●Typical Transient Thermal Characteristics

Symbol	Value	Unit
R _{th1}	1.24E-01	
R _{th2}	3.92E-01	K/W
R _{th3}	1.54E-01	

Symbol	Value	Unit
C_{th1}	3.81E-03	
C_{th2}	4.44E-03	Ws/K
C_{th3}	6.02E-02	



•Electrical characteristic curves

Fig.1 V_F - I_F Characteristics

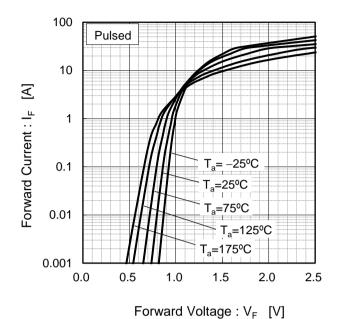
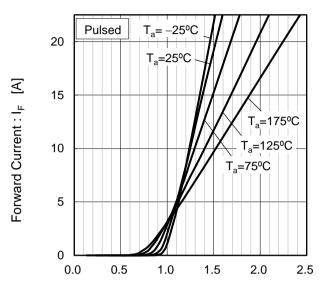


Fig.2 V_F - I_F Characteristics



Forward Voltage : V_F [V]

Fig.3 V_R - I_R Characteristics

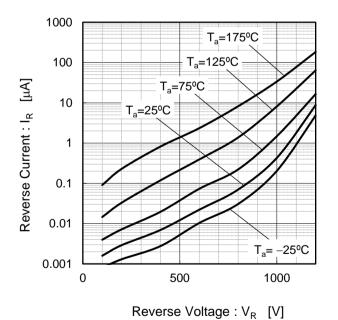
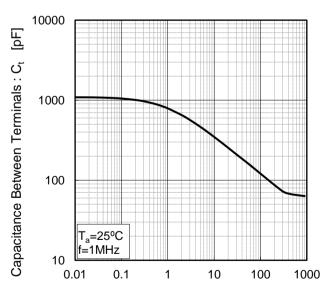


Fig.4 V_R - C_t Characteristics



Reverse Voltage : V_R [V]

•Electrical characteristic curves

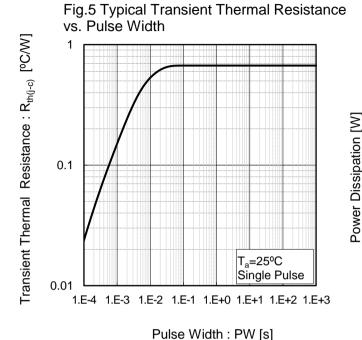
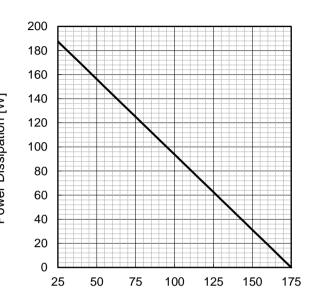
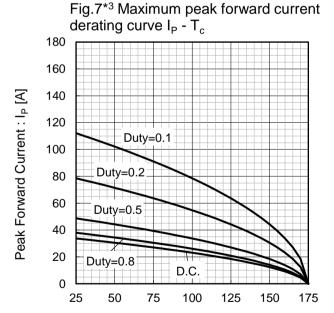


Fig.6 Power Dissipation



Case Temperature : T_c [°C]



Case Temperature : T_c [°C]
*3 Based on max Vf, max R_{th(j-c)}
Valid for switching of above 10kHz, excluding D.C. curve.

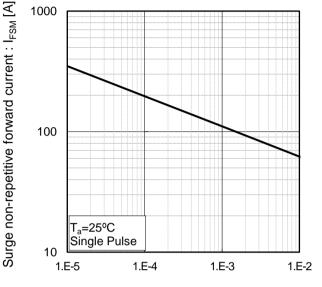
derating curve I_P - T_c (Not guaranteed) 180 160 Duty=0.1 Peak Forward Current: Ip [A] 140 120 Duty=0.2 100 80 Duty=0.5 60 40 20 Duty=0.8 D.C. 0 25 50 75 100 125 150 175

Fig.8*4 Typical peak forward current

Case Temperature : T_c [°C] *4 Based on typ Vf, typ R_{th(j-c)} Typical value, not guaranteed Valid for switching of above 10kHz, excluding D.C. curve

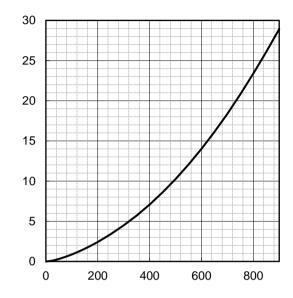
• Electrical characteristic curves

Fig.9 Surge non-repetitive forward current vs. Pulse width (Sinusoidal waveform)



Pulse Width: PW [s]

Fig.10 Typical capacitance store energy

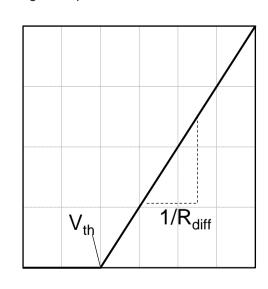


Capacitance stored energy : E_C[μJ]

Reverse Voltage: V_R [V]

Symplified forward characteristic model

Fig.11 Equivalent forward current curve



Forward Voltage : $V_{\rm F}$

$$V_F = V_{th} + R_{diff} I_F$$

$$\begin{aligned} &V_{th} \left(\ T_{j} \ \right) = a_{0} + a_{1} \, T_{j} \\ &R_{diff} \left(\ T_{j} \ \right) = b_{0} + b_{1} \, T_{j} + b_{2} \, T_{j}^{2} \end{aligned}$$

Symbol	Typical Value	Unit
a_0	9.93E-01	V
a ₁	-1.27E-03	V/°C
b ₀	2.43E-02	Ω
b ₁	1.37E-04	Ω/°C
b ₂	8.87E-07	$\Omega/^{\circ}C^{2}$

 T_i in °C; -55 °C < T_i < °C; I_F < 30 A

Forward Current: IF

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